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Ultrahigh Green and Red Optical Gain Cross- sections from Solutions of Colloidal Quantum Well Heterostructures

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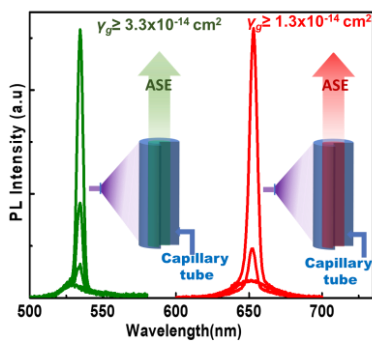
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Here, we demonstrate amplified spontaneous emission (ASE) in solution with ultralow thresholds of $30 \mu\text{J}/\text{cm}^2$ in red and of $44 \mu\text{J}/\text{cm}^2$ in green from engineered colloidal quantum well (CQW) heterostructures. For this purpose, CdSe/CdS core/crown CQWs, designed to hit the green region, and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs, further tuned to reach the red region by shell alloying, were employed to achieve high-performance ASE in the visible. The net modal gain of these CQWs reaches 530 cm^{-1} for the green and 201 cm^{-1} for the red, two to three orders of magnitude larger than those of colloidal quantum dots (QDs) in solution. To explain the root cause for ultrahigh gain coefficient in solution, we show that for the first time that the gain cross-sections of these CQWs is $\geq 3.3 \times 10^{-14} \text{ cm}^2$ in the green and $\geq 1.3 \times 10^{-14} \text{ cm}^2$ in the red which are two orders magnitude larger compared to those of CQDs.

TOC Image



Colloidal quantum wells (CQWs) present an excellent platform as gain media owing to their solution processability, wide tunability of emission colour,¹⁻⁴ giant oscillator strength,^{1,5} large gain cross-section,⁶ slow Auger rates⁷⁻⁹ and ultra-narrow emission profiles.^{1,3,10} Especially the giant gain cross-section and slow Auger recombination of CQWs make them extremely attractive candidates for optical gain studies and applications as these are the critical factors for satisfying the gain condition.¹¹ Lasing and amplified spontaneous emission (ASE) with ultralow thresholds^{2,7-8,12-15} and large net modal gains^{7,14,16} from solid films of close-packed CQWs have been widely studied. Although solution-based gain medium can be highly advantageous because of the enhanced photostability owing to constant replenishment of gain media by the flux of nanocrystals and flexibility of incorporation into optical cavities, there are only very few reports of optical gain in solution using colloidal nanocrystals.^{6,17-20} This is primarily due to the low concentration of gain media possible in solution, limiting the feasible levels of gain coefficients. While thin solid films of nanocrystals may lead to lower thresholds and larger modal gains due to the increased density of gain media, such films are more likely to suffer from surface roughness affecting the waveguiding and optical confinement,²¹⁻²³ nonradiative losses due to Förster resonance energy transfer (FRET) and homo-FRET,²⁴⁻²⁵ and reproducibility of the identical samples.

In-solution optical gain can be achieved straightforwardly by employing a simple glass tube¹⁷ or a cuvette^{6,18} serving possibly as a cavity and a host along with highly concentrated nanocrystal solution serving as a gain medium. In this approach, uniform gain media in a cavity can be achieved robustly and reproducibly, and loss mechanisms, such as nonradiative homo-FRET and scattering of light due to aggregations of nanocrystals, are conveniently suppressed. Such a gain medium can be utilized in microfluidic networks to achieve on-chip lasing for optical sensing and detection.²⁶⁻³⁰ Despite the foreseeable advantages of CQWs, including the modal gain reaching levels one order of magnitude larger than those of the quantum dots and

nanorods,¹⁶ slow Auger rates^{7-9,31} and gain cross-sections with three orders of magnitude larger than the quantum dots,⁶ there is only one previously reported work on CQW based optical gain in solution to date which was achieved by multiphoton pumping using a cuvette-based Fabry–Perot resonator.⁶

Here, we present the achievement of in-solution ASE from green-emitting CdSe/CdS core/crown CQWs and red CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs enabling ultralow thresholds of 44 $\mu\text{J}/\text{cm}^2$ and 30 $\mu\text{J}/\text{cm}^2$, respectively, in solution. The net modal gains of green CdSe/CdS core/crown CQWs and red CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs at this concentration reach $\sim 530\text{ cm}^{-1}$ and $\sim 201\text{ cm}^{-1}$, respectively. In addition, we report for the first time the gain cross-section of these heterostructures of CQWs, which are found to be $\geq 3.3 \times 10^{-14}\text{ cm}^2$ for the green-emitting CdSe/CdS core/crown CQWs and $\geq 1.3 \times 10^{-14}\text{ cm}^2$ for the red-emitting CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs. These obtained gain cross-sections are two orders of magnitude larger than those of QDs^{11,17} and hence show the vast potential of CQWs as in-solution optical gain media.

For the purpose of systematic study of optical gain in solution, we synthesized CdSe/CdS core/crown CQWs³² to hit the green spectral range and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs³³ to reach the red range, both using high quality 4 monolayer (ML) CdSe CQWs as the seeds. Transmission electron microscopy (TEM) images of the CdSe core CQWs and CdSe/CdS core/crown CQWs are shown in Figures 1(a) and 1(b), respectively. The lateral area was measured to be $\sim 150\text{ nm}^2$ for the core CQWs and $\sim 350\text{ nm}^2$ for the core/crown CQWs.

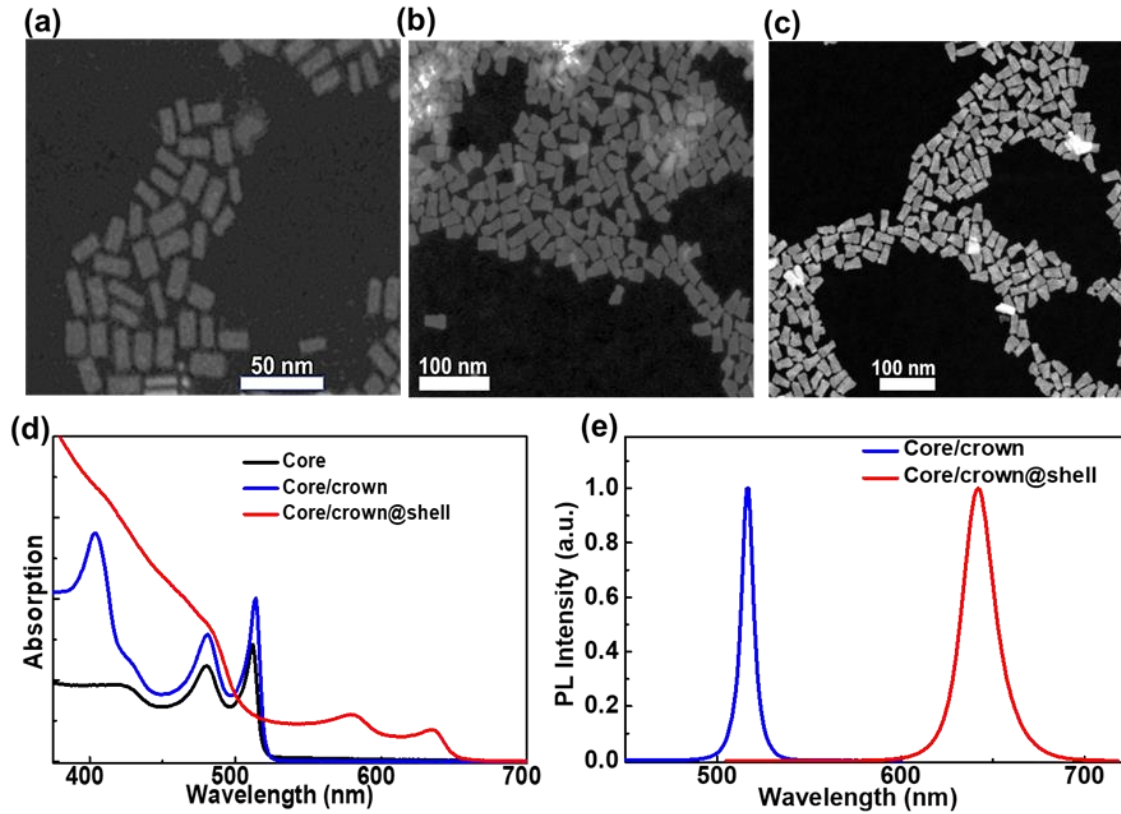


Figure 1. TEM images of (a) 4 ML CdSe, (b) 4 ML CdSe/CdS core/crown and (c) 12 ML CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs. (d) Absorption spectra of CdSe, CdSe/CdS core/crown and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs. (e) PL spectra of CdSe/CdS core/crown and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs.

To further obtain the CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs, 4 ML thick gradient alloyed shell of Cd_xZn_{1-x}S was grown on the previously synthesized CdSe/CdS core/crown CQWs to push the emission peak towards red.³³ Details of the synthesis of CQWs are provided in the Supporting Information (SI). Owing to the gradient alloyed shell of Cd_xZn_{1-x}S, charge carriers feel soft potential confinement in the vertical dimension,³³ which is also highly desirable for optical gain applications due to the suppression of Auger recombination.³⁴ A representative TEM image of these core/crown@gradient-alloyed shell CQWs is presented in Figure 1(c).

The absorption profiles of the CdSe core, CdSe/CdS core/crown and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs are given in Figure 1(d). The absorption cross-sections of CdSe/CdS core/crown and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs are $1.1 \times 10^{-13} \text{ cm}^2$ and $2.9 \times 10^{-13} \text{ cm}^2$, respectively, at 400 nm, which were calculated using a method provided in our previous publication.³⁵ The intrinsic absorption coefficients $\mu_i(\lambda)$ of the CdSe/CdS core/crown and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs, which are obtained by dividing the absorption cross-sections at the wavelength of interest by the physical volume of the CQWs, are $1.96 \times 10^5 \text{ cm}^{-1}$ and $2.1 \times 10^4 \text{ cm}^{-1}$, respectively, at their heavy hole absorption peak. It is worth mentioning that the intrinsic absorption is an important parameter showing the gain capability of a material since the material gain $g(\lambda)$ at a specific wavelength is equal to the intrinsic absorption coefficient $\mu_i(\lambda)$ of the material at the same wavelength.³⁶ The photoluminescence (PL) spectra of CdSe/CdS core/crown and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs in solution are shown in Figure 1(e). The PL peak of the core/crown CQWs is at ~517 nm (in solution) with a full-width-half-maximum (FWHM) of 8 nm while that of CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs (in solution) is at ~642 nm with a FWHM of ~21 nm.

To explore the ASE performance of our CQWs in solution, CQWs dispersed in toluene were inserted into a capillary tube having an inner diameter of 300 μm by the help of capillary force. The higher boiling point (compared to most of non-polar solvents, such as commonly used hexane), the lower volatility and the relatively high refractive index of toluene make it our choice of solvent. Figure 2(a) shows pump-fluence dependence of the ASE spectra from CdSe/CdS core/crown CQWs. The sharp ASE peak can be observed at 534.2 nm with a FWHM of 4.3 nm at room temperature on the red side of the spontaneous emission for the pump fluences above the threshold. This red shift of ASE ($\approx 5 \text{ nm}$) with respect to the spontaneous emission confirms multiexcitonic gain.³⁷ This sort of red shift in ASE is desirable for optical

gain since this hinders self-absorption.^{7,38} Total emission intensity as a function of the pump fluence for the green-emitting CQWs is presented in Figure 2(b). Using this data, the ASE threshold is calculated to be $44 \mu\text{J}/\text{cm}^2$, which is lower than any previously reported ASE threshold in solution for nanocrystals. Previously, the best reported threshold in solution for colloidal nanocrystals is $\sim 105 \mu\text{J}/\text{cm}^2$ from CsPbBr_3 perovskite nanocrystals.¹⁸

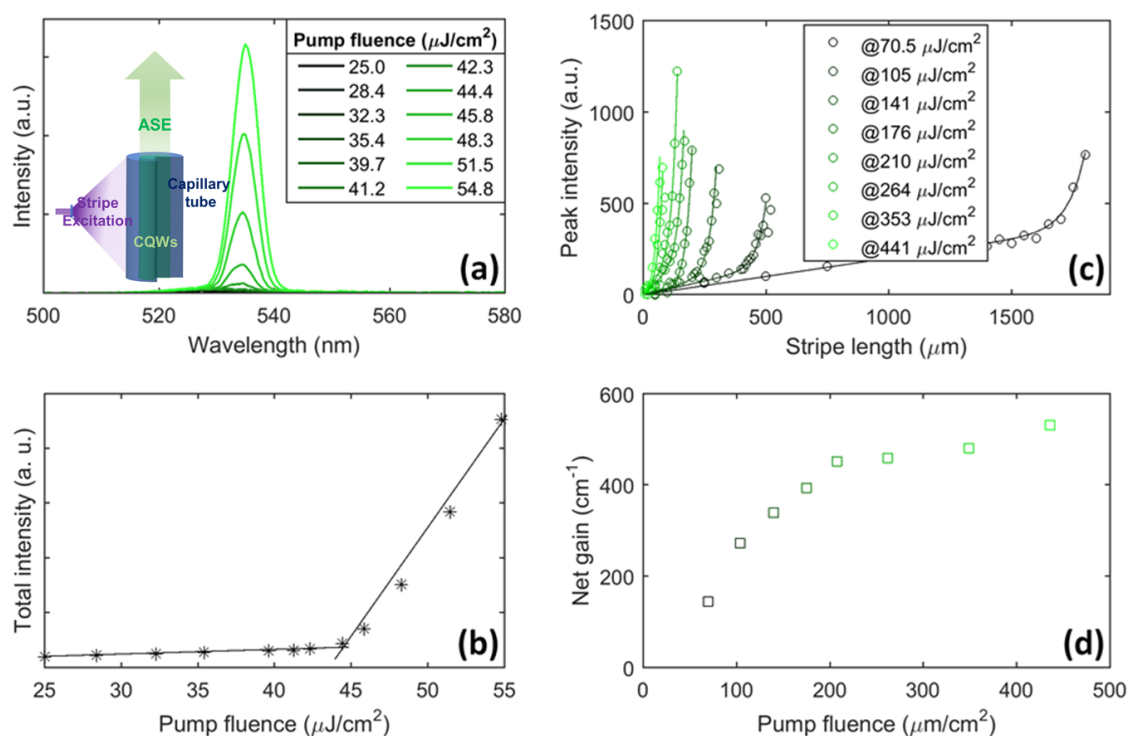


Figure 2. Optical gain performance of in-solution CdSe/CdS core/crown CQWs. (a) Collected optical spectra at different pump fluences. Inset of (a) shows a schematic of CQW solution in the capillary tube optically pumped using stripe geometry for ASE measurements. (b) Emission intensity as a function of the pump fluence. (c) Emission intensity as a function of the excitation stripe length. (d) Extracted net gain coefficients as a function of the pump fluence.

We used variable-stripe-length (VSL) method³⁹ to determine the modal gain of CQWs in solution at various pump fluences higher than the optical gain threshold. Figure 2(c) displays total emission intensities at different pump fluences as a function of the stripe length. Figure 2(d) presents the pump-dependent net modal gain coefficient at various pump fluences obtained

from the fittings presented in Figure 2(c). As can be seen in Figure 2(d), the net modal gain increases linearly at lower fluences above the threshold and saturates around $\sim 530 \text{ cm}^{-1}$. Although these net modal gains are nearly one order of magnitude lower than their solid films^{7,16} due to lower concentration of CQWs, these net modal gains are similar to the net modal gains of solid films of quantum dots and nanorods⁴⁰⁻⁴³ and two to three orders of magnitude larger than that of QDs in solution.¹⁷

The gain cross-section per CQW (γ_g) can be calculated by

$$g_{net} = C \times \Gamma \times \gamma_g - \alpha \quad (1)$$

where C is the concentration of CQWs, Γ is the optical confinement factor, and α is the optical loss coefficient.⁶ In our case, C is $\sim 1.7 \times 10^{16} \text{ cm}^{-3}$ ($\sim 28.3 \text{ }\mu\text{M}$) in toluene, g_{net} is known at different pump fluences as presented in Figure 2(d), and Γ is calculated by numerically solving the supported optical modes, as will be discussed next. Here, we assume that the net modal gain is close to the modal gain (g) for optical gain in solution.⁶ In fact, our net modal gain levels (530 cm^{-1} for CdSe/CdS core/crown CQWs and 201 cm^{-1} for CdSe/CdS@Cd_xZn_{1-x}S core/crown@ shell CQWs) are much larger than even the loss coefficient from films of CQWs ($\sim 10 \text{ cm}^{-1}$),²² which are expected to suffer larger loss in film compared to in solution. In addition, we added term Γ into the equation (1) to account for the optical confinement factor in the active optical gain media.

Here, Γ was calculated by obtaining the electrical field distribution in our system. Γ for a mode is defined as the ratio of the modal power inside the excited portion of the gain media to the total modal power:

$$\Gamma = \int_{\substack{\text{excited} \\ \text{gain region}}} \frac{1}{2} \text{Re}\{\vec{E} \times \vec{H}^*\} \cdot \hat{z} dx dy / \int_{-\infty}^{\infty} \frac{1}{2} \text{Re}\{\vec{E} \times \vec{H}^*\} \cdot \hat{z} dx dy \quad (2)$$

where \vec{E} and \vec{H} are the electric and magnetic fields of the specified mode, respectively. The gain cross-section γ_g can be found by computing Γ for the modes that are guided and confined. The modal power distributions for the first four modes (HE_{11} , HE_{21} , HE_{31} , HE_{12}) for CdSe/CdS core/crown CQWs are presented in Figure 3(a-d). The confinement factor peaks at 0.94 for HE_{11} due to strong overlap with the excitation. Based on this maximal Γ , we computed the minimum gain cross-section of CdSe/CdS core/crown CQWs using the modal gain value of 530 cm^{-1} and the concentration of $1.7 \times 10^{16} \text{ cm}^{-3}$. The obtained value of gain cross-section for CdSe/CdS core/crown CQWs is $\geq 3.3 \times 10^{-14} \text{ cm}^2$, which is 2 orders of magnitude larger than the gain cross-section of QDs¹⁷ having gain profiles saturating approximately twice of their thresholds, suggesting a limited number of carrier species contributing gain in the case of QDs. We attribute this extremely large gain cross-section of CQWs to the high number of density of states in the CQWs.

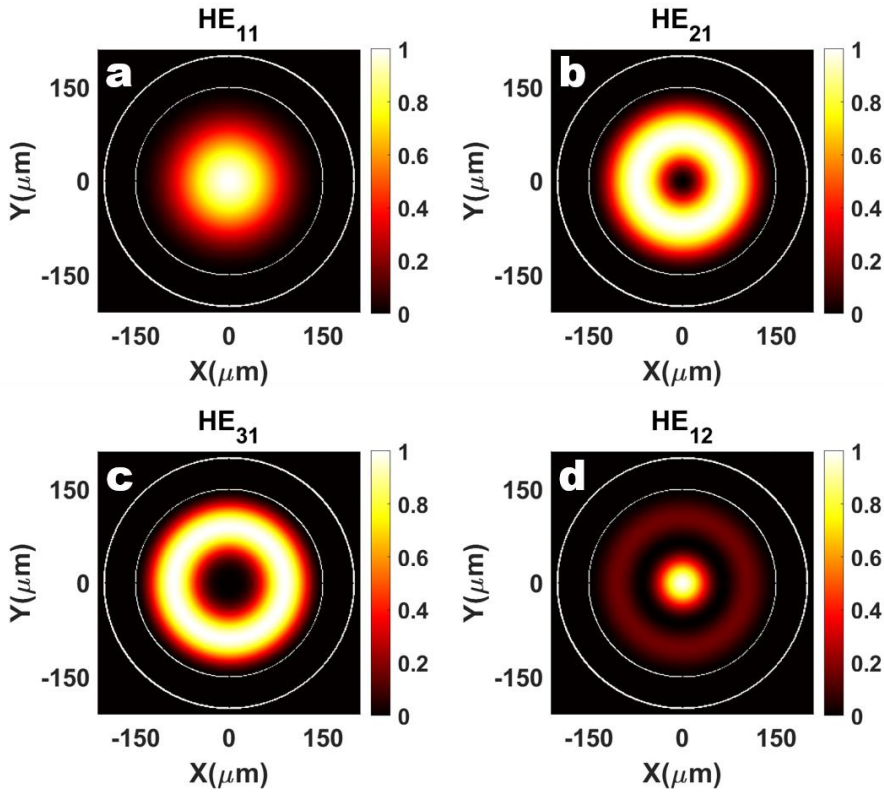


Figure 3. (a-d) Modal guided power distributions at 534 nm for the first four modes. The boundaries of the fiber are indicated with white concentric rings with large ring ($r = 200 \text{ }\mu\text{m}$)

corresponding to the air-cladding boundary and small ring ($r = 150 \mu\text{m}$) corresponding to cladding-core boundary. Due to the large fiber parameter V and a similar refractive index of our CQW solutions, the calculated profiles at 653 nm and 534 nm are practically identical. The reason behind the near-unity confinement factor for HE_{11} is easily understood from the regional overlap between mode and the excitation (see Figure S3).

Figure 4(a) presents the pump-fluence dependence of ASE spectra from the solution of $\text{CdSe/CdS}@\text{Cd}_x\text{Zn}_{1-x}\text{S}$ core/crown@gradient-alloyed shell CQWs. In these CQWs, the spontaneous emission peaks at 651.9 nm with a FWHM of 29.0 nm. As the pump intensity increases, a sharp peak emerges at 653.0 nm with a FWHM of 6.0 nm and ultimately surpasses the PL spectrum at stronger pump fluences. The reduced red shift of ASE in this sample compared to that of the core/crown one can be attributed to the multiexcitonic gain with quasi-type-II band alignment profile. Total emission intensity as a function of the pump fluence is given in Figure 4(b). The ASE threshold for these red-emitting CQWs is $30 \mu\text{J}/\text{cm}^2$, which is lower than that of the green core/crown CQWs. This reduction in the gain threshold can be attributed to the further efficient suppression of Auger recombination in these alloyed-shell CQW heterostructures compared to the core/crown CQWs as a result of the graded alloying providing a soft confinement potential.^{7,34} Figure 4(c) shows total emission intensities at different pump fluences as a function of the stripe length and the net modal gain coefficients at various pump fluences obtained from the fittings given in Figure 4(c) are presented in Figure 4(d). As shown in Figure 4(d), the net modal gain saturates around 201 cm^{-1} at a pump fluence of $\sim 350 \mu\text{J}/\text{cm}^2$. This maximum net modal gain from these red CQWs in solution is two orders of magnitude higher than that of CdZnS/ZnS alloyed-core/shell QDs¹⁷ and similar to that of core/shell CQWs.⁶ Modal characteristics of the red-emitting CQWs are identical to CdSe/CdS core/crown CQWs due to the large fiber parameter V and similar refractive index of CQW solutions, and hence both CQW solutions share the same Γ value of 0.94 at the ASE peak

wavelength. For these red CQWs, the gain cross-section is found to be $\geq 1.3 \times 10^{-14} \text{ cm}^2$. However, the gain cross-section of these core/crown@gradient-alloyed shell CQWs is lower than that of core/crown CQWs ($\sim 3.3 \times 10^{-14} \text{ cm}^2$). This is also reflected by the lower absorption coefficient of the core/crown@gradient-alloyed shell CQWs compared to the core/crown CQWs. This can be explained by the quasi type-II band alignment of thicker core/crown@gradient-alloyed shell CQWs, which effectively reduces the oscillator strength of the transitions in the core/crown@gradient-alloyed shell CQWs. On the other hand, the intriguingly lower threshold of the core/crown@gradient-alloyed shell CQWs is dominantly dictated by their larger absorption cross-section at the excitation wavelength and stronger suppression of Auger recombination as compared to the core/crown CQWs.

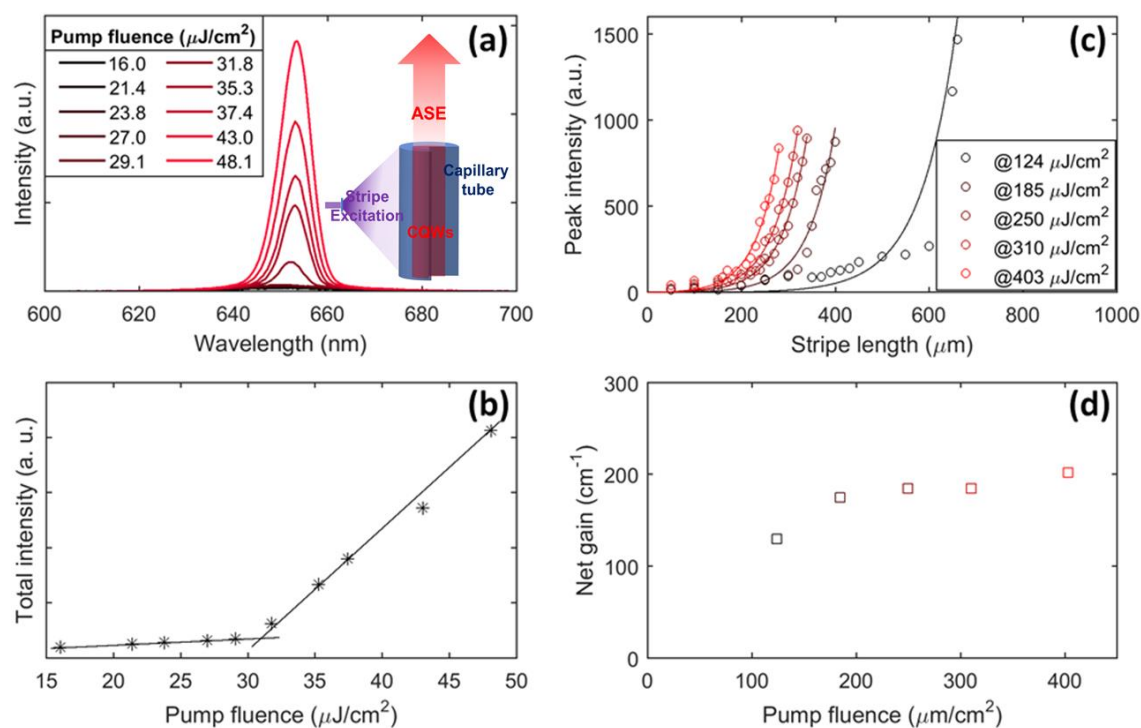


Figure 4. Optical gain performance of in-solution CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs. (a) Collected optical spectra at different pump fluences. Inset of (a) displays a schematic of CQW solution in the capillary tube pumped using stripe geometry for ASE measurements. (b) Emission intensity as a function of the pump

fluence. (c) Emission intensity as a function of the excitation stripe length. (d) Extracted net gain coefficients as a function of the pump fluence.

In summary, we demonstrated ASE in solution using CdSe/CdS core/crown CQWs designed to emit in green and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs tuned to emit in red dispersed in toluene with ultralow thresholds of 44 μJ/cm² and 30 μJ/cm², respectively. The net modal gain coefficient of these green and red reaches ~530 cm⁻¹ and ~201 cm⁻¹, respectively, at a concentration of ~1.7×10¹⁶ cm⁻³, which are two to three orders of magnitude larger than that of QDs in solution.¹⁷ The gain cross-sections of the green CdSe/CdS core/crown CQWs and the red CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs are ≥3.3×10⁻¹⁴ cm² and ≥1.3×10⁻¹⁴ cm², respectively. The obtained gain cross-sections are two orders of magnitude larger than the gain cross-section of QDs and can be attributed to the higher available number of density of states in CQWs. These solution-processed CQWs with their exceptional properties as a solution-based optical gain medium presents extraordinary opportunities for the design and implementation of solution-based lasers, which can be integrated conveniently and intimately into microfluidic devices designed for sensing and imaging applications.

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Supporting Information

Synthesis of CdSe/CdS core/crown CQWs and CdSe/CdS@Cd_xZn_{1-x}S core/crown@gradient-alloyed shell CQWs, time resolved PL measurements, details of the optical gain experiments and numerical calculations for optical confinement factor.

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